2SC2209

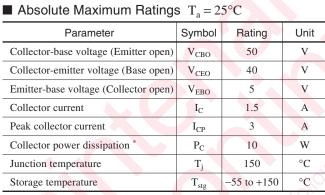
Silicon NPN epitaxial planar type

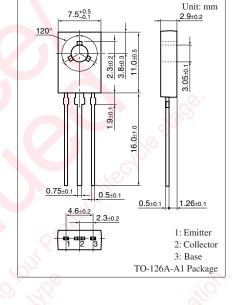
For low-frequency power amplification Complementary to 2SA0963

■ Features

- Large collector power dissipation P_C
- Output of 5 W can be obtained by a complementary pair with 2SA0963

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	50	V	
Collector-emitter voltage (Base open)	V _{CEO}	40	V	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I_{C}	1.5	A	
Peak collector current	I_{CP}	3	A	
Collector power dissipation *	P _C	10	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	





Note) *: $T_C = 25^{\circ}C$

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

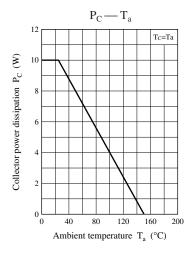
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_C = 1 \text{ mA}, I_E = 0$	50	350		V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	40	0		V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20 \text{ V}, I_{E} = 0$	250		1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 \text{ V}, I_{B} = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			10	μΑ
Forward current transfer ratio *1, 2	h _{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ A}$	80		220	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 1.5 \text{ A}, I_B = 0.15 \text{ A}$			1	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 2 A, I_B = 0.2 A$			1.5	V
Transition frequency	f_T	$V_{CB} = 5 \text{ V}, I_E = -0.5 \text{ A}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		50		pF

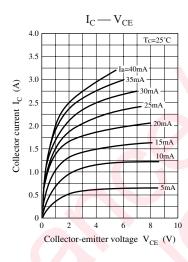
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

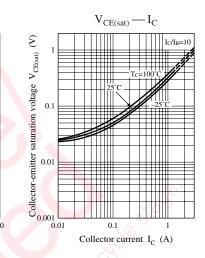
2. *1: Pulse measurement

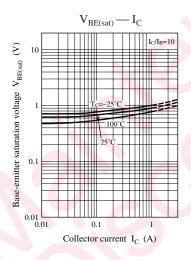
*2: Rank classification

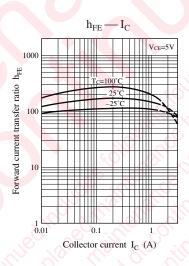
Rank	Q	R
h_{FE}	80 to 160	120 to 220

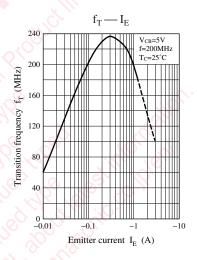


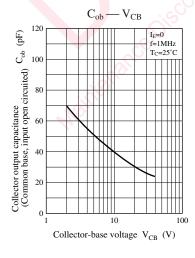


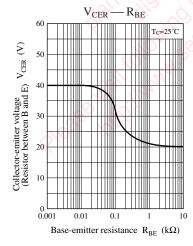


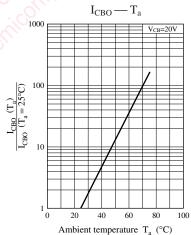


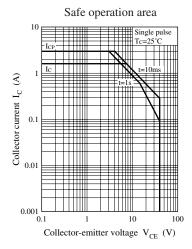












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